



ULB121

NPN SILICON TRANSISTOR

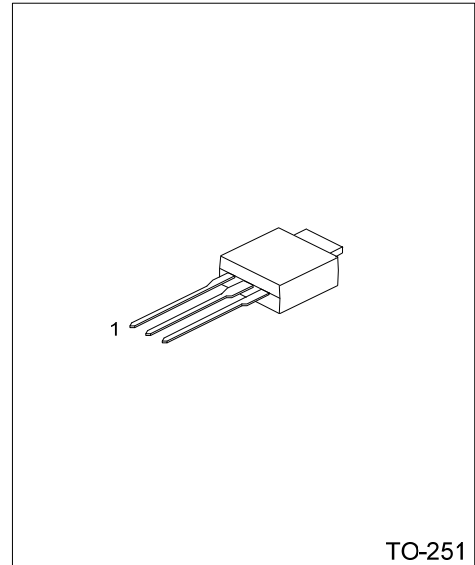
NPN TRIPLE DIFFUSED PLANAR TYPE HIGH VOLTAGE TRANSISTOR

■ DESCRIPTION

The UTC **ULB121** is a medium power transistor designed for use in switching applications.

■ FEATURES

- * High breakdown voltage
- * Low collector saturation voltage
- * Fast switching speed
- * Halogen Free



■ ORDERING INFORMATION

Ordering Number	Package	Pin Assignment			Packing
		1	2	3	
ULB121G-TM3-T	TO-251	B	C	E	Tube

ULB121G-TM3-T	(1) Packing Type (2) Package Type (3) Halogen Free	(1) T: Tube (2) TM3: TO-251 (3) G: Halogen Free
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■ ABSOLUTE MAXIMUM RATING ($T_A=25^\circ\text{C}$)

PARAMETER		SYMBOL	RATINGS	UNIT
Collector-Base Voltage		V_{CBO}	600	V
Collector-Emitter Voltage		V_{CEO}	400	V
Emitter-Base Voltage		V_{EBO}	6	V
Collector Current	DC	I_C	300	mA
	Pulse		600	mA
Base Current	DC	I_B	40	mA
	Pulse		100	mA
Total Power Dissipation ($T_C=25^\circ\text{C}$)		P_D	10	W
Junction Temperature		T_J	150	$^\circ\text{C}$
Storage Temperature		T_{STG}	-40 ~ +150	$^\circ\text{C}$

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged.

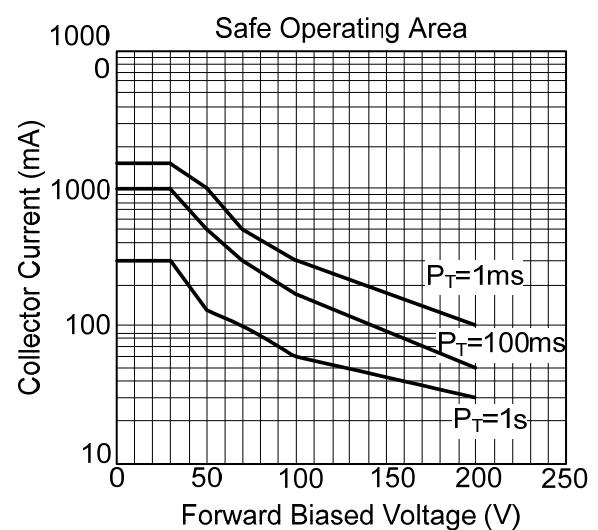
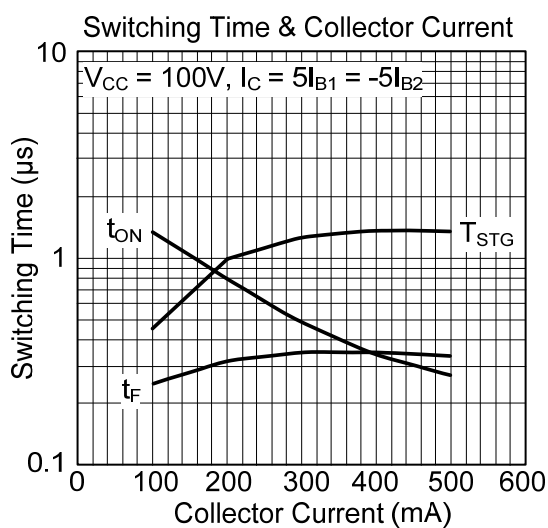
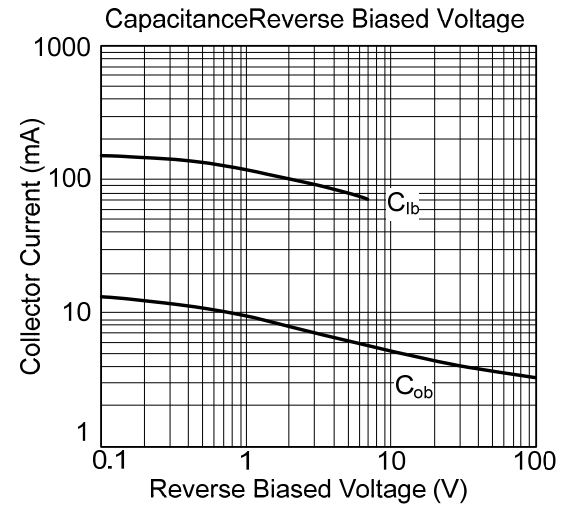
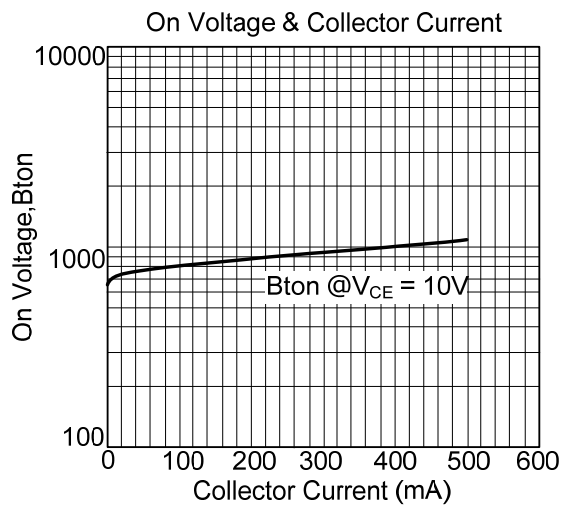
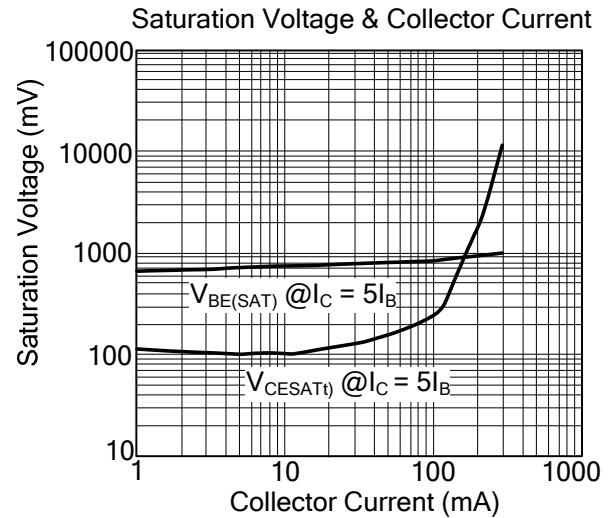
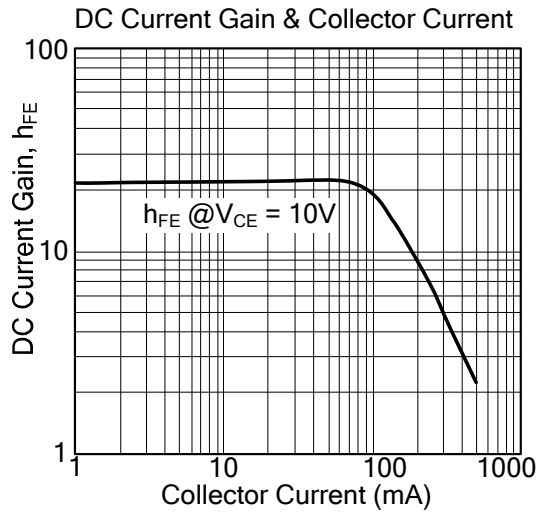
Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ ELECTRICAL CHARACTERISTICS ($T_A=25^\circ\text{C}$, unless otherwise specified.)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS						
Collector-Base Breakdown Voltage	BV_{CBO}	$I_C=100\mu\text{A}$	600			V
Collector-Emitter Breakdown Voltage	BV_{CEO}	$I_C=10\text{mA}$	400			V
Emitter-Base Breakdown Voltage	BV_{EBO}	$I_E=10\mu\text{A}$	6			V
Collector Cutoff Current	I_{CBO}	$V_{CB}=550\text{V}$			10	μA
Collector Cutoff Current	I_{CEO}	$V_{CB}=400\text{V}$			10	μA
Emitter Cutoff Current	I_{EBO}	$V_{EB}=6\text{V}$			10	μA
ON CHARACTERISTICS						
DC Current Gain(Note)	h_{FE1}	$V_{CE}=10\text{V}, I_C=10\text{mA}$	8			
	h_{FE2}	$V_{CE}=10\text{V}, I_C=50\text{mA}$	10		36	
Collector-Emitter Saturation Voltage (Note)	$V_{CE(SAT)}$	$I_C=50\text{mA}, I_B=10\text{mA}$			400	mV
		$I_C=100\text{mA}, I_B=20\text{mA}$			750	
Base-Emitter Saturation Voltage (Note)	$V_{BE(SAT)}$	$I_C=50\text{mA}, I_B=10\text{mA}$			1	V

Note: Pulse Test : Pulse Width $\leq 380\mu\text{s}$, Duty Cycle $\leq 2\%$

■ TYPICAL CHARACTERISTICS



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